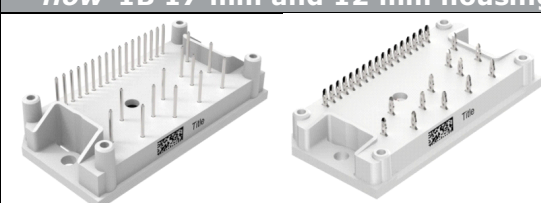
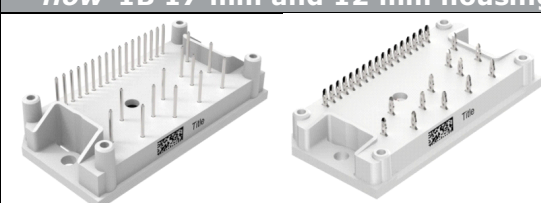
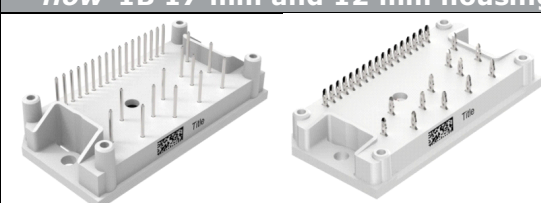
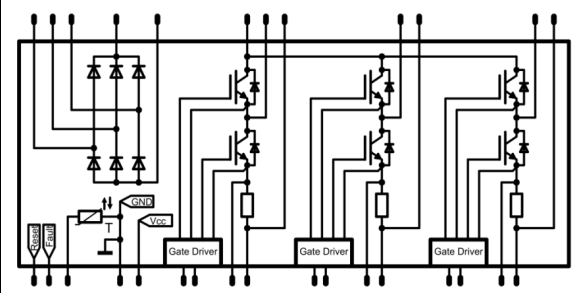
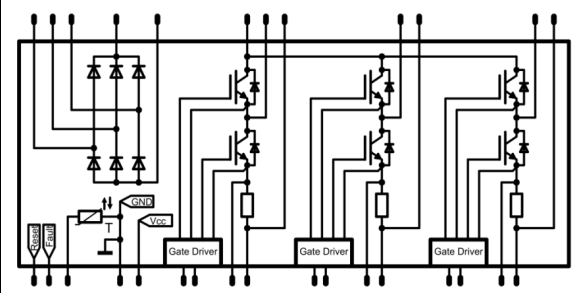
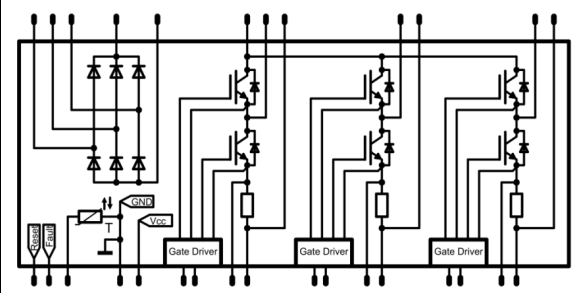




<i>flow</i> IPM 1B-CI	1200 V / 8 A					
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## Maximum Ratings

$T_j = 25\text{ }^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
<b>Rectifier Diode</b>				
Peak Repetitive Reverse Voltage	$V_{RRM}$		1600	V
Continuous (direct) forward current	$I_F$	$T_j = T_{jmax}$ $T_s = 80\text{ }^\circ\text{C}$	13	A
Surge (non-repetitive) forward current	$I_{FSM}$	50 Hz Single Half Sine Wave	150	A
Surge current capability	$I^2t$	$t_p = 10\text{ ms}$ $T_j = 45\text{ }^\circ\text{C}$	110	$\text{A}^2\text{s}$
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80\text{ }^\circ\text{C}$	15	W
Maximum Junction Temperature	$T_{jmax}$		150	$^\circ\text{C}$



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**20-1B12IPA008SC-L239C09**  
**20-FB12IPA008SC-L239C08Y**  
datasheet

## Maximum Ratings

$T_j = 25\text{ °C}$ , unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
<b>Inverter Switch</b>				
Collector-emitter voltage	$V_{CES}$		1200	V
Collector current	$I_C$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	9	A
Repetitive peak collector current	$I_{CRM}$	$t_p$ limited by $T_{jmax}$	24	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	23	W
Gate-emitter voltage	$V_{GES}$		$\pm 20$	V
Short circuit ratings	$t_{SC}$	$T_j \leq 150\text{ °C}$	10	$\mu s$
	$V_{CC}$	$V_{GE} = 15\text{ V}$	800	V
Maximum Junction Temperature	$T_{jmax}$		175	$^{\circ}C$
<b>Inverter Diode</b>				
Peak Repetitive Reverse Voltage	$V_{RRM}$		1200	V
Continuous (direct) forward current	$I_F$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	8	A
Repetitive peak forward current	$I_{FRM}$		15	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	12	W
Maximum Junction Temperature	$T_{jmax}$		150	$^{\circ}C$
<b>Gate Driver</b>				
Supply voltage	$V_{CC}$		24	V
Logic input voltage	$V_{in}$	U-Hin, U-Lin, V-Hin, V-Lin, W-Hin, W-Lin FAULT, RESET	$-0,5 \dots V_{cc} + 0,5$	V
Internal current limit	$I_{MAX}$		5	A
Junction Temperature	$T_{jmax}$		125	$^{\circ}C$



## Maximum Ratings

$T_j = 25\text{ °C}$ , unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
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### Inverter Shunt

DC forward current	$I_F$		9	A
Power dissipation	$P_{tot}$		2,43	W

### Module Properties

#### Thermal Properties

Storage temperature	$T_{stg}$		-40...+125	°C
Operation temperature under switching condition	$T_{jop}$		-40...(T <sub>jmax</sub> - 25)	°C

#### Isolation Properties

Isolation voltage	$V_{isol}$	DC Test Voltage $t_p = 2\text{ s}$	4000	V
Creepage distance			min. 12,7	mm
Clearance		Press-fit pins / solder pins	min. 12,7 / 12,69	mm
Comparative Tracking Index	CTI		> 200	



Vincotech

**20-1B12IPA008SC-L239C09**  
**20-FB12IPA008SC-L239C08Y**  
 datasheet

## Characteristic Values

Parameter	Symbol	Conditions					Value			Unit
		$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_C$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max		

### Rectifier Diode

#### Static

Forward voltage	$V_F$				7	25 125		1,04 0,97	1,11	V
Reverse leakage current	$I_r$			1600		25			10	μA

#### Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	phase-change material $\lambda = 3,4$ W/mK						4,56		K/W
-------------------------------------	---------------	---	--	--	--	--	--	------	--	-----

### Inverter Switch

#### Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{GE} = V_{CE}$				0,00015	25	5,3	5,8	6,3	V
Collector-emitter saturation voltage	$V_{CEsat}$		15		8	25 150		1,58	1,85 2,25	2,07	V
Collector-emitter cut-off current	$I_{CES}$		0	1200		25				1	μA
Gate-emitter leakage current	$I_{GES}$		20	0		25				120	nA
Internal gate resistance	$r_g$								none		Ω
Input capacitance	$C_{ies}$								490		pF
Reverse transfer capacitance	$C_{res}$	$f = 1$ MHz	0	25		25			30		

#### Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	phase-change material $\lambda = 3,4$ W/mK							4,22		K/W
-------------------------------------	---------------	---	--	--	--	--	--	--	------	--	-----

#### Dynamic

Turn-on delay time*	$t_{d(on)}$	$V_{CC} = 15$ V			600	8	25		1484		ns
							125		1909		
Rise time	$t_r$						25		12		
							125		16		
Turn-off delay time*	$t_{d(off)}$						25		1436		
		125		1916							
Fall time	$t_f$			25		77					
				125		136					
Turn-on energy (per pulse)	$E_{on}$	$Q_{t-FWD} = 1$ μC					25		0,399		mWs
		$Q_{t-FWD} = 1,7$ μC					125		0,630		
Turn-off energy (per pulse)	$E_{off}$						25		0,520		
							125		0,844		

\* times include gate driver deadtime



## Characteristic Values

Parameter	Symbol	Conditions					Value			Unit
		$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V]	$I_C$ [A] $I_D$ [A]	$I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max	

### Inverter Diode

#### Static

Forward voltage	$V_F$				7,5	25 125		1,65 1,61		V
Reverse leakage current	$I_r$			1200		25			250	μA

#### Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	phase-change material $\lambda = 3,4$ W/mK						5,69		K/W
-------------------------------------	---------------	---	--	--	--	--	--	------	--	-----

#### Dynamic

Peak recovery current	$I_{RRM}$	$di/dt = 336$ A/μs $di/dt = 481$ A/μs	15	600	8	25 125		8 8		A
Reverse recovery time	$t_{rr}$					25 125		320 514		ns
Recovered charge	$Q_r$					25 125		0,975 1,748		μC
Reverse recovered energy	$E_{rec}$					25 125		0,433 0,785		mWs
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25 125		56 37		A/μs

### Inverter Shunt

Resistance	$R$							30		mΩ
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### Characteristic Values

Parameter	Symbol	Conditions					Value			Unit
		$V_{GE}$ [V]	$V_{CE}$ [V]	$I_C$ [A]	$T_j$ [°C]	Min	Typ	Max		

#### Gate Driver\*

##### Static

Recommended supply voltage	$V_{CC}$					13,5	15	20	V
Power on reset trip voltage	$V_{POR}$					4,0	5,5	7,5	V
Internal current limit	$I_{MAX}$					13,3	16,7	20	A
Quiescent supply current	$I_q$						3	4,5	mA
Logic "1" input voltage	$V_{IH}$	UH, UL, VH, VL, WH, WL, RST				2,2	3	4	v
Logic "0" input voltage	$V_{IL}$		0,6	1,5	2,1	v			
Logic "1" input current	$I_{inH}$	$V_{in} = 5$ V				0,6	1	1,4	mA
Logic "0" input current	$I_{inL}$	$V_{in} = 0$ V				0	0	0,01	mA
Input signal filter time	$t_{Filt}$	UH, UL, VH, VL, WH, WL, FO (in), RST (pulse)				80	200	500	ns
Logic "1" FAULT output**	$V_{outFAULTH}$							0,95	V
Logic "1" FAULT input treshold voltage**	$V_{inFAULTH}$					0,6	1,5	2,1	V
Logic "0" FAULT input treshold voltage**	$V_{inFAULTL}$					2,2	3	4	V
Under voltage reset voltage	$V_{UVreset}$					10	10,8	11,6	V
Under voltage trip voltage	$V_{UVtrip}$					10,5	11,3	12,1	V
Under voltage hysteresis voltage	$V_{UVhysteresis}$					0,2	0,5	0,8	V
Under voltage filter time	$t_{uvfilt}$					4	8	16	µs
Internal dead time	$t_{uvjit}$	Delay matching, high side turn-on and low side turn off				-100	80	300	ns
Internal dead time	$t_{uvjit}$	Delay matching, low side turn-on and high side turn off				-20	180	400	ns

\* For more information see Mitsubishi's M81738FP datasheet. The recommended minimum input pulse width is 2 µs.

\*\* FAULT active low with pull up resistor to Vcc.



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### Characteristic Values

Parameter	Symbol	Conditions					Value			Unit
		$V_{GS}$ [V]	$V_{GE}$ [V]	$V_{DS}$ [V]	$V_F$ [V]	$I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	

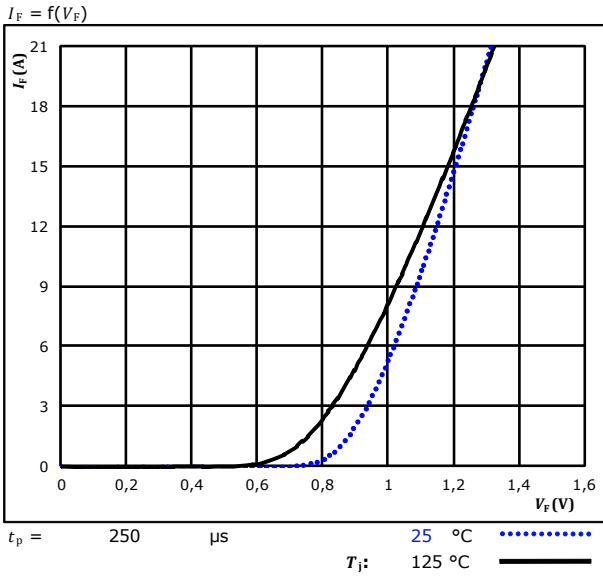
#### Thermistor

Rated resistance	$R$					25		22		k $\Omega$
Deviation of $R_{100}$	$\Delta_{R/R}$	$R_{100} = 1486 \Omega$				100	-12		+14	%
Power dissipation	$P$					25		200		mW
Power dissipation constant						25		2		mW/K
B-value	$B_{(25/50)}$	Tol. $\pm 3\%$				25		3950		K
B-value	$B_{(25/100)}$	Tol. $\pm 3\%$				25		3998		K
Vincotech NTC Reference									B	

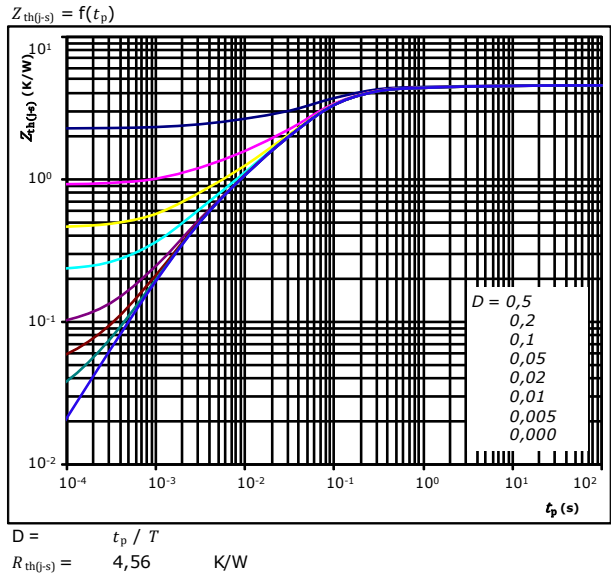


## Rectifier Diode Characteristics

**figure 1. Rectifier Diode**  
**Typical forward characteristics**



**figure 2. Rectifier Diode**  
**Transient thermal impedance as a function of pulse width**



Diode thermal model values

$R$ (K/W)	$\tau$ (s)
1,1300E-01	8,9590E+00
2,5930E-01	8,4330E-01
1,9540E+00	1,0960E-01
1,7280E+00	3,6370E-02
5,0510E-01	3,4450E-03



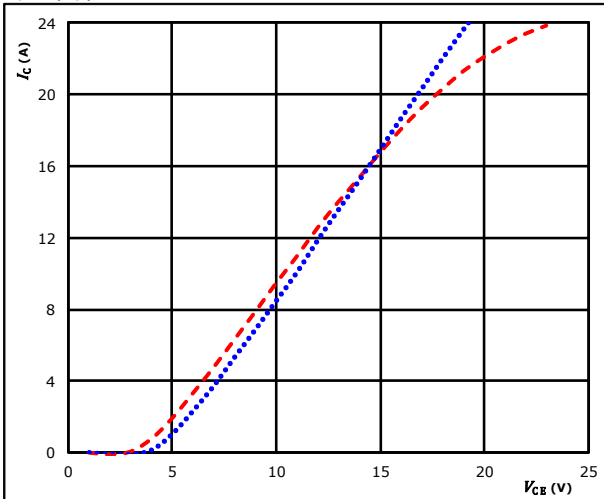


## Inverter Switch Characteristics

**figure 1. IGBT**

**Typical output characteristics**

$I_C = f(V_{CE})$

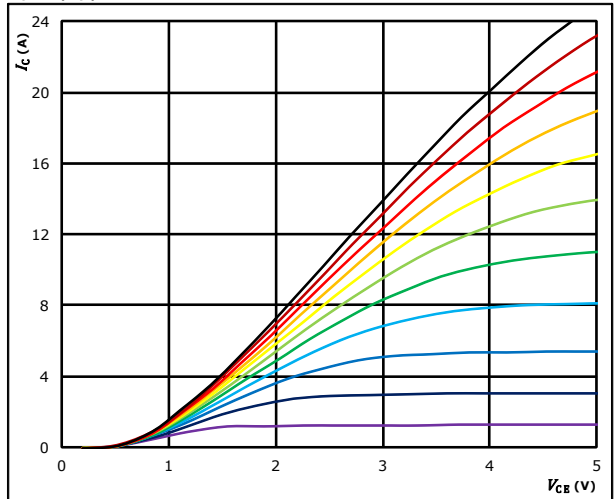


$t_p = 250 \mu\text{s}$        $T_j: 25 \text{ }^\circ\text{C}$       .....  
 $V_{GE} = 15 \text{ V}$        $T_j: 150 \text{ }^\circ\text{C}$       - - - - -

**figure 2. IGBT**

**Typical output characteristics**

$I_C = f(V_{CE})$

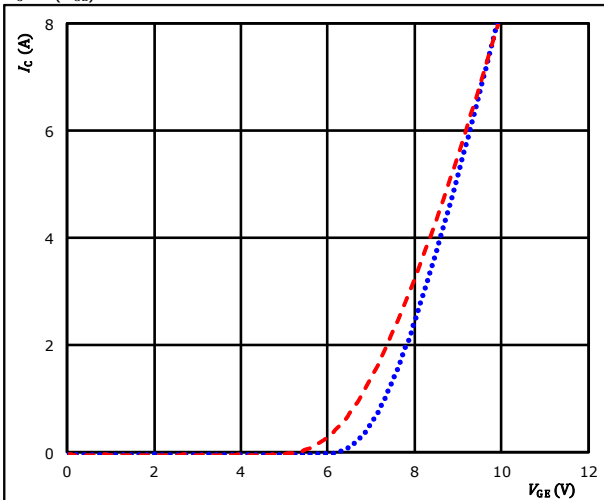


$t_p = 250 \mu\text{s}$   
 $T_j = 150 \text{ }^\circ\text{C}$   
 $V_{GE}$  from 7 V to 17 V in steps of 1 V

**figure 3. IGBT**

**Typical transfer characteristics**

$I_C = f(V_{GE})$

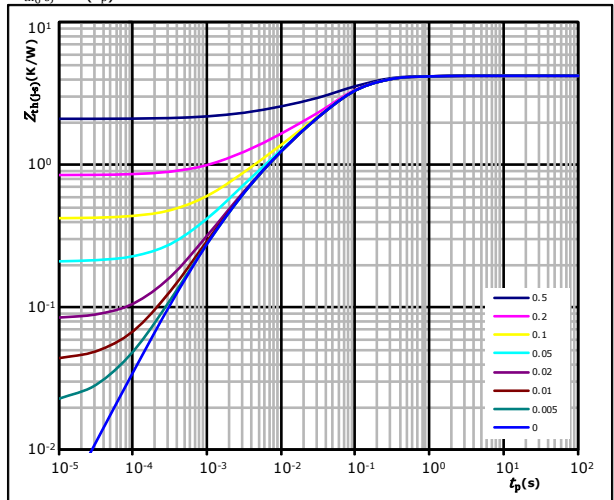


$t_p = 100 \mu\text{s}$        $T_j: 25 \text{ }^\circ\text{C}$       .....  
 $V_{CE} = 10 \text{ V}$        $T_j: 150 \text{ }^\circ\text{C}$       - - - - -

**figure 4. IGBT**

**Transient Thermal Impedance as function of Pulse duration**

$Z_{th(j-s)} = f(t_p)$



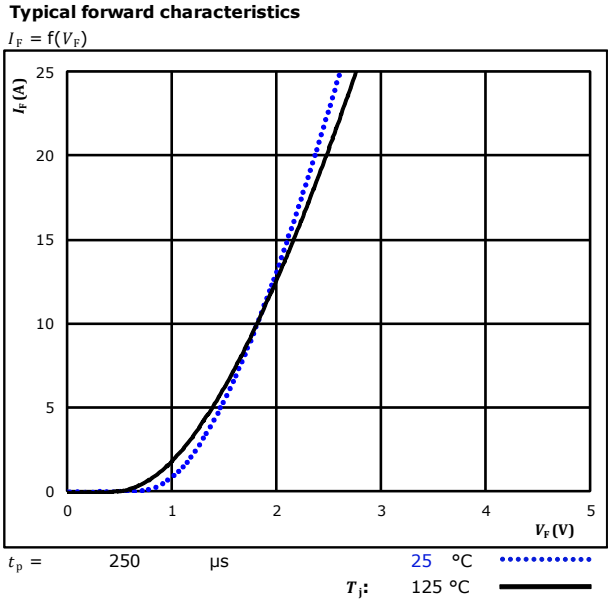
$D = t_p / T$   
 $R_{th(j-s)} = 4,22 \text{ K/W}$   
 IGBT thermal model values

$R \text{ (K/W)}$	$\tau \text{ (s)}$
2,57E+00	6,96E-02
7,15E-01	1,68E-02
5,14E-01	3,47E-03
9,91E-02	7,30E-04

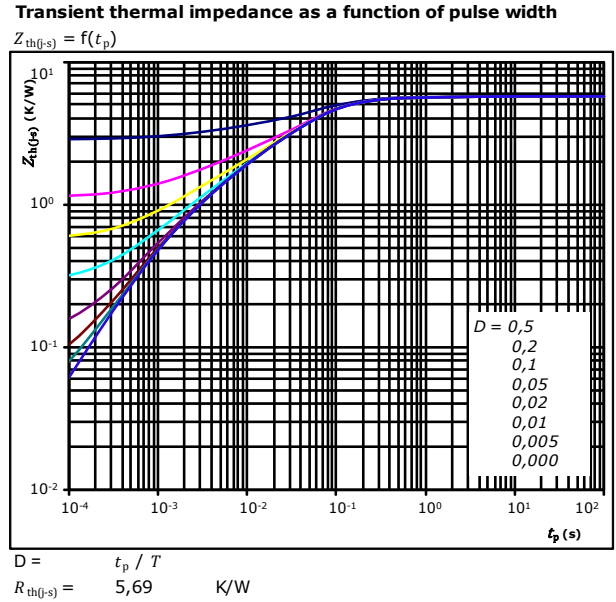


## Inverter Diode Characteristics

**figure 1.** FWD



**figure 2.** FWD

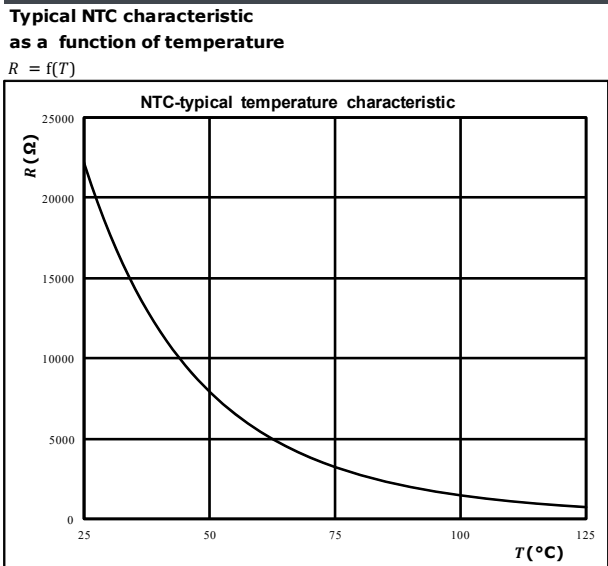


FWD thermal model values

$R$ (K/W)	$\tau$ (s)
1,733E-01	2,116E+00
1,301E+00	1,400E-01
2,883E+00	4,111E-02
9,535E-01	5,372E-03
3,778E-01	1,029E-03

## Thermistor Characteristics

**figure 1.** Thermistor

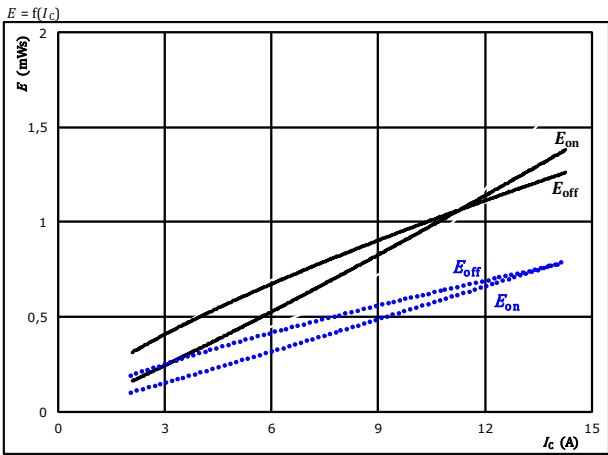




## Inverter Switching Characteristics

**figure 1. IGBT**

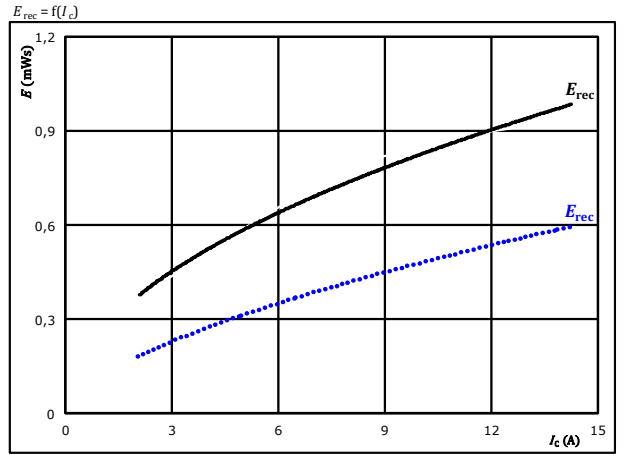
Typical switching energy losses as a function of collector current



With an inductive load at  
 $V_{CE} = 600$  V  
 $V_{CC} = 15$  V  
 $V_{IN} = 5$  V  
 $T_j = 25$  °C (dotted blue line)  
 $T_j = 125$  °C (solid black line)

**figure 2. FWD**

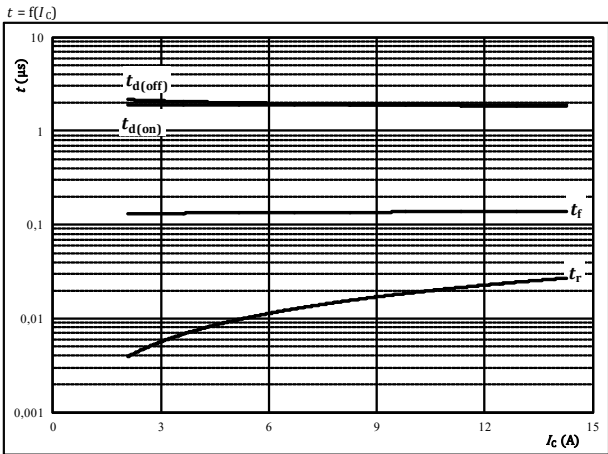
Typical reverse recovered energy loss as a function of collector current



With an inductive load at  
 $V_{CE} = 600$  V  
 $V_{CC} = 15$  V  
 $V_{IN} = 5$  V  
 $T_j = 25$  °C (dotted blue line)  
 $T_j = 125$  °C (solid black line)

**figure 3. IGBT**

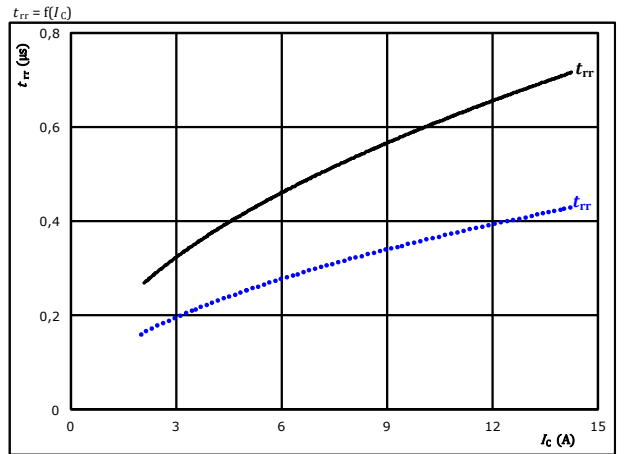
Typical switching times as a function of collector current



With an inductive load at  
 $T_j = 125$  °C  
 $V_{CE} = 600$  V  
 $V_{CC} = 15$  V  
 $V_{IN} = 5$  V

**figure 4. FWD**

Typical reverse recovery time as a function of collector current



At  
 $V_{CE} = 600$  V  
 $V_{CC} = 15$  V  
 $V_{IN} = 5$  V  
 $I_C = 8$  A  
 $T_j = 25$  °C (dotted blue line)  
 $T_j = 125$  °C (solid black line)

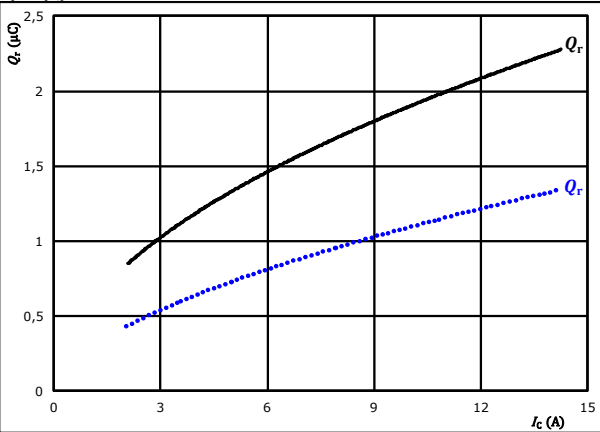


## Inverter Switching Characteristics

**figure 5.** FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$

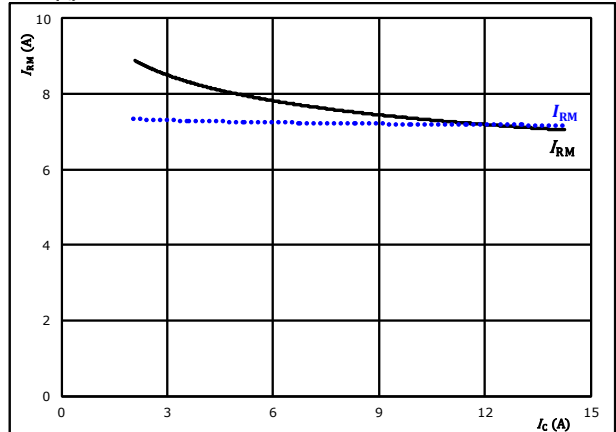


At  $V_{CE} = 600$  V  $T_j: 25$  °C .....  
 $V_{CC} = 15$  V  $T_j: 125$  °C ———  
 $V_{IN} = 5$  V

**figure 6.** FWD

Typical peak reverse recovery current current as a function of collector current

$$I_{RM} = f(I_c)$$

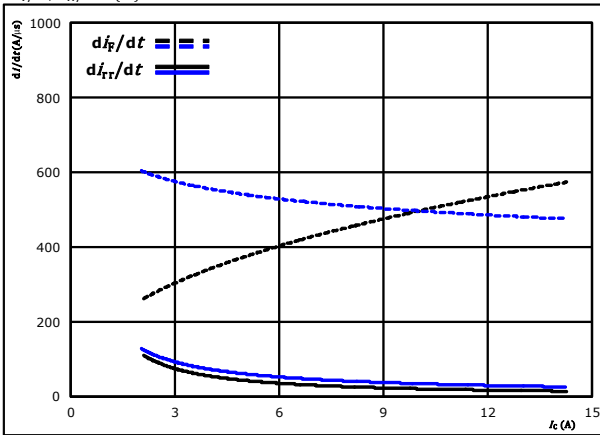


At  $V_{CE} = 600$  V  $T_j: 25$  °C .....  
 $V_{CC} = 15$  V  $T_j: 125$  °C ———  
 $V_{IN} = 5$  V  
 $V_{GE} = 15$  V  
 $I_c = 8$  A

**figure 7.** FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current

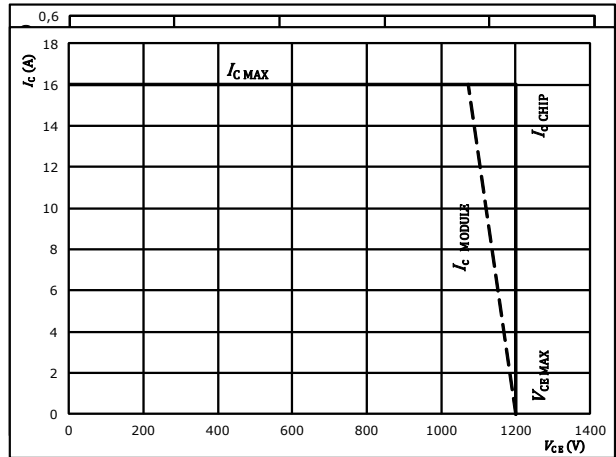
$$di_f/dt, di_{rr}/dt = f(I_c)$$



At  $V_{CE} = 600$  V  $T_j: 25$  °C .....  
 $V_{CC} = 15$  V  $T_j: 125$  °C ———  
 $V_{IN} = 5$  V

**figure 8.** IGBT

Reverse bias safe operating area



At  $T_j = 175$  °C



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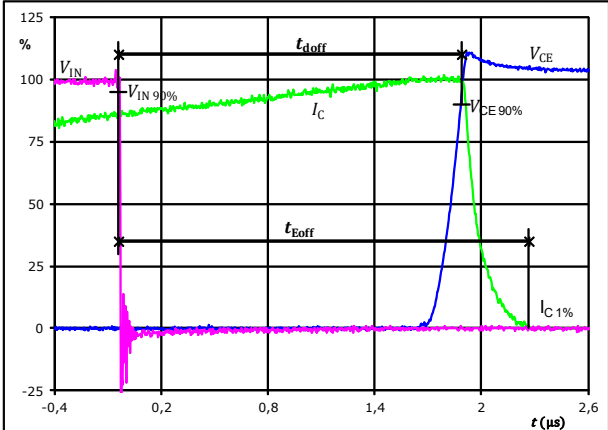
## Inverter Switching Characteristics

General conditions

$T_j$	=	125 °C
$V_{CC}$	=	15 V

**Figure 1.** IGBT

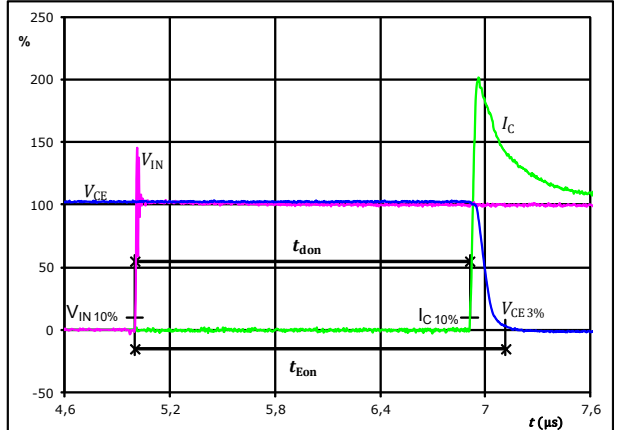
Turn-off Switching Waveforms & definition of  $t_{doff}$ ,  $t_{Eoff}$  ( $t_{Eoff}$  = integrating time for  $E_{off}$ )



$V_{IN}$ (0%) =	0	V
$V_{IN}$ (100%) =	15	V
$V_C$ (100%) =	600	V
$I_C$ (100%) =	8	A
$t_{doff}$ =	1,916	$\mu$ s
$t_{Eoff}$ =	2,308	$\mu$ s

**Figure 2.** IGBT

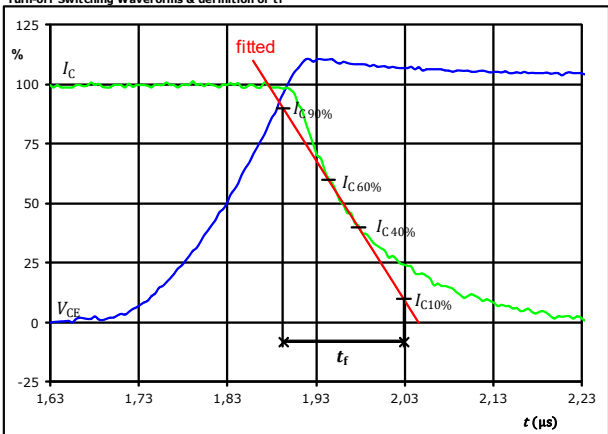
Turn-on Switching Waveforms & definition of  $t_{don}$ ,  $t_{Eon}$  ( $t_{Eon}$  = integrating time for  $E_{on}$ )



$V_{IN}$ (0%) =	0	V
$V_{IN}$ (100%) =	15	V
$V_C$ (100%) =	600	V
$I_C$ (100%) =	8	A
$t_{don}$ =	1,909	$\mu$ s
$t_{Eon}$ =	2,116	$\mu$ s

**Figure 3.** IGBT

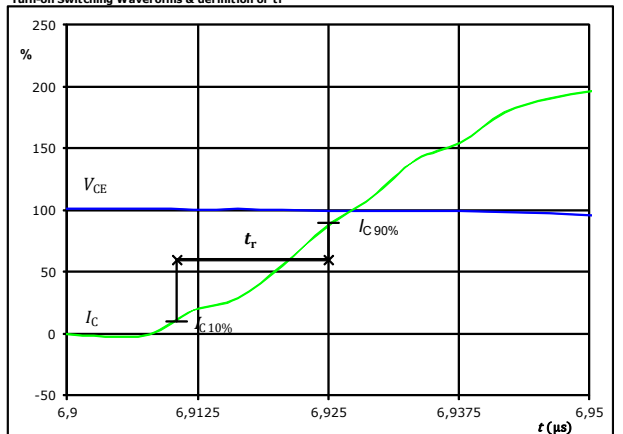
Turn-off Switching Waveforms & definition of  $t_f$



$V_C$ (100%) =	600	V
$I_C$ (100%) =	8	A
$t_f$ =	0,136	$\mu$ s

**Figure 4.** IGBT

Turn-on Switching Waveforms & definition of  $t_r$



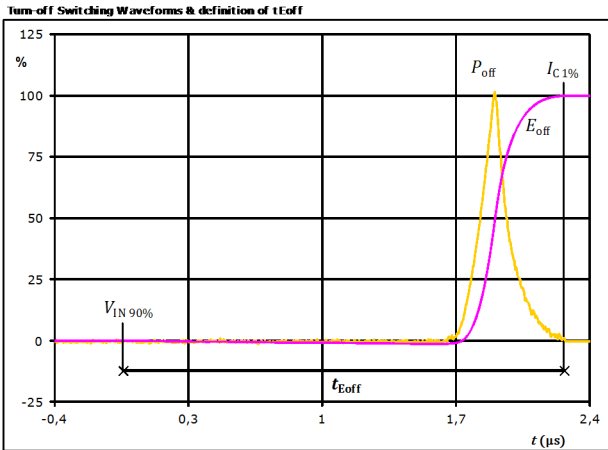
$V_C$ (100%) =	600	V
$I_C$ (100%) =	8	A
$t_r$ =	0,016	$\mu$ s



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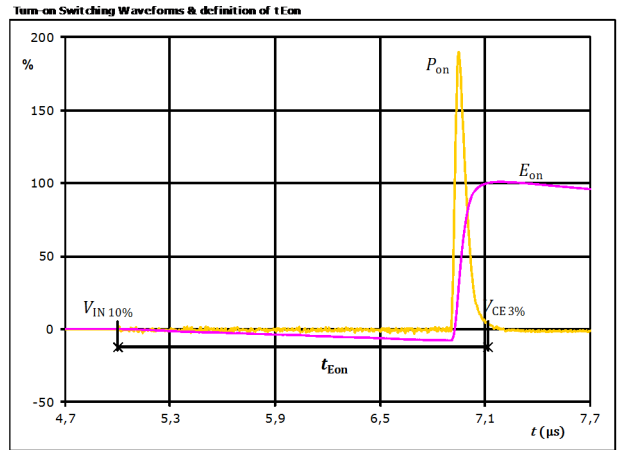
## Inverter Switching Characteristics

**Figure 5.** IGBT



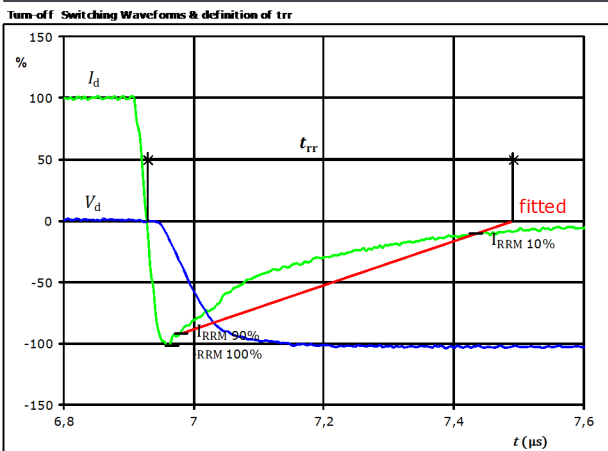
$P_{off}(100\%) = 4,85$  kW  
 $E_{off}(100\%) = 0,84$  mJ  
 $t_{Eoff} = 2,31$   $\mu$ s

**Figure 6.** IGBT



$P_{on}(100\%) = 4,85$  kW  
 $E_{on}(100\%) = 0,63$  mJ  
 $t_{Eon} = 2,12$   $\mu$ s

**Figure 7.** FWD

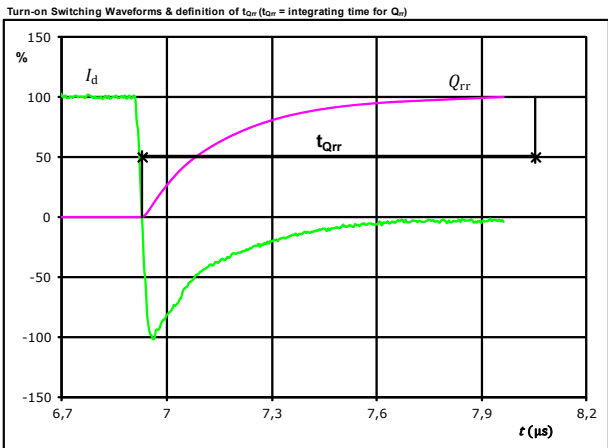


$V_d(100\%) = 600$  V  
 $I_d(100\%) = 8$  A  
 $I_{RRM}(100\%) = -8$  A  
 $t_{rr} = 0,514$   $\mu$ s



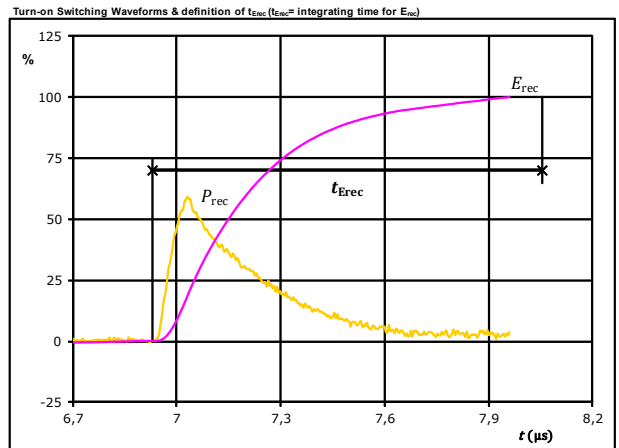
## Inverter Switching Characteristics

**Figure 8.** FWD



$I_d$ (100%) =	8	A
$Q_{rr}$ (100%) =	1,75	$\mu\text{C}$
$t_{Qrr}$ =	1,13	$\mu\text{s}$

**Figure 9.** FWD



$P_{rec}$ (100%) =	4,85	kW
$E_{rec}$ (100%) =	0,79	mJ
$t_{Erec}$ =	1,13	$\mu\text{s}$



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**20-1B12IPA008SC-L239C09**  
**20-FB12IPA008SC-L239C08Y**  
 datasheet

Ordering Code & Marking						
Version			Ordering Code			
without thermal paste 17 mm housing with solder pins			20-1B12IPA008SC-L239C09			
without thermal paste 12 mm housing with press-fit pins			20-FB12IPA008SC-L239C08Y			
with thermal paste 17 mm housing with solder pins			20-1B12IPA008SC-L239C09-/3/			
with thermal paste 12 mm housing with press-fit pins			20-FB12IPA008SC-L239C08Y-/3/			
	Text	Name	Date code	UL & VIN	Lot	Serial
		NN-NNNNNNNNNNNNNN-TTTTTWW		WWYY	UL VIN	LLLLL
	Datamatrix	Type&Ver	Lot number	Serial	Date code	
		TTTTTTTV	LLLLL	SSSS	WWYY	

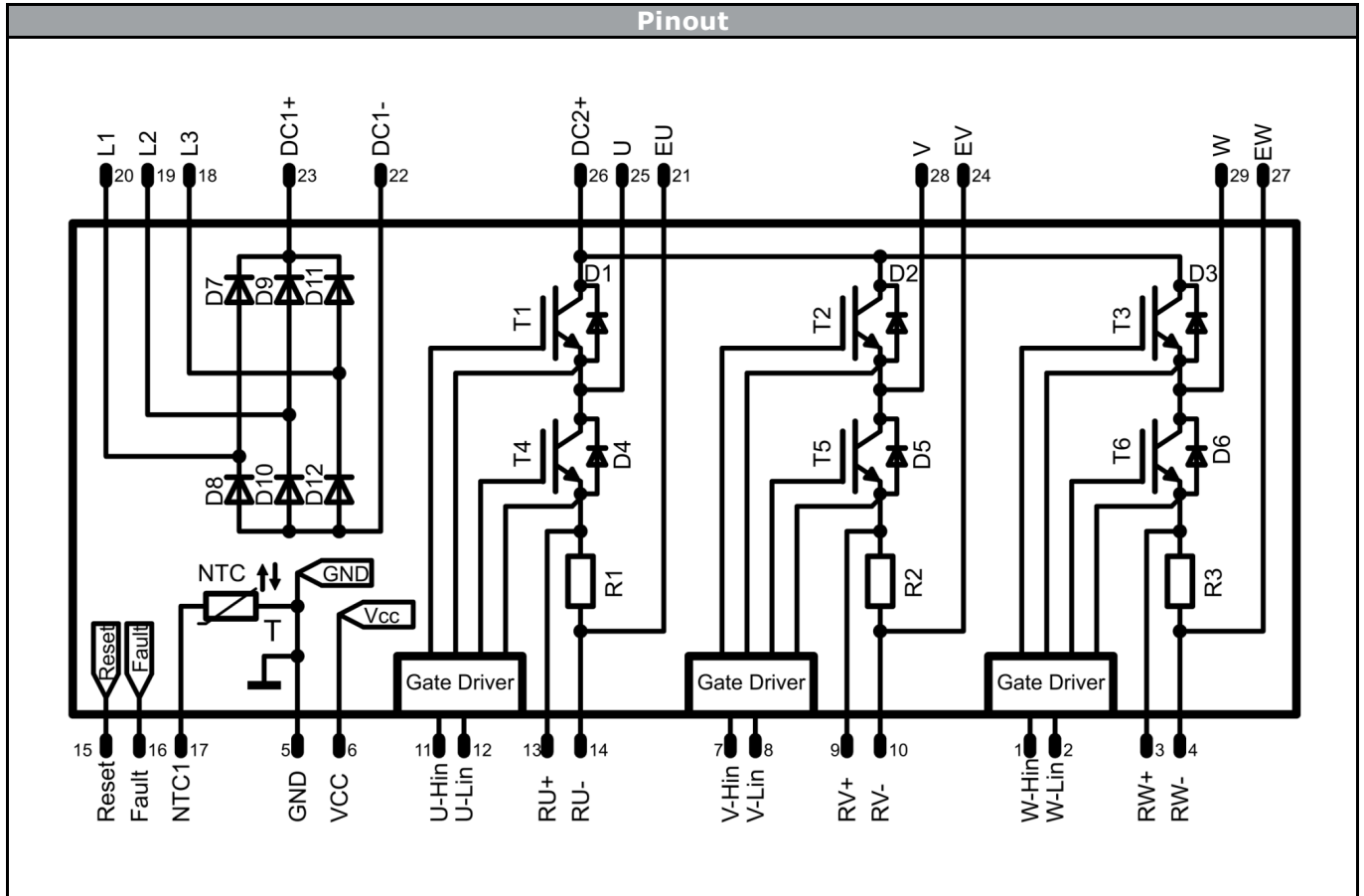
Pin table [mm]				Outline	
Pin	X	Y	Function		
1	45,1	0	WH	17 mm Solder pin 	
2	42,4	0	WL		
3	39,7	0	RW+		
4	37	0	RW-		
5	34,3	0	GND		
6	31,6	0	VCC		
7	28,9	0	VH		
8	26,2	0	VL		
9	23,5	0	RV+		
10	20,8	0	RV-		
11	18,1	0	UH		
12	15,4	0	UL		
13	12,7	0	RU+		
14	10	0	RU-		
15	7,3	0	RST		
16	4,6	0	FO		
17	1,9	0	NTC		
18	0	8,8	L3	12 mm Press-fit 	
19	0	17,8	L2		
20	3,8	26,1	L1		
21	7,8	13,3	EU		
22	9	18,7	DC1-		
23	14,2	26,1	DC1+		
24	20,6	17,8	EV		
25	24,7	26,1	U		
26	28,7	21,6	DC2+		
27	36,2	16,7	EW		
28	37,5	26,1	V		
29	45,1	21,9	W		

Pin Descriptions			Power pin descriptions		
Pin	Function	Description	Pin	Function	Description
1	W-HIN	Signal input for high-side W phase	18	L3	Rectifier input L3
2	W-LIN	Signal input for low-side W phase	19	L2	Rectifier input L2
3	RW+	W phase shunt +	20	L1	Rectifier input L1
4	RW-	W phase shunt -	21	EU	Open emitter U phase
5	GND	Signal ground	22	DC1-	Rectifier output DC-
6	VCC	Driver circuit supply voltage	23	DC1+	Rectifier output DC+
7	V-HIN	Signal input for high-side V phase	24	EV	Open emitter V phase
8	V-LIN	Signal input for low-side V phase	25	U	Output U phase
9	RV+	V phase shunt +	26	DC2+	Inverter input DC+
10	RV-	V phase shunt -	27	EW	Open emitter W phase
11	U-HIN	Signal input for high-side U phase	28	V	Output V phase
12	U-LIN	Signal input for low-side U phase	29	W	Output W phase
13	RU+	U phase shunt +			
14	RU-	U phase shunt -			
15	RESET	Fault latch reset (min. 500ns pulse)			
16	~FAULT	Fault latch input/output (negative logic, open drain)			
17	NTC	Temperature sensor connector			





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<b>Identification</b>					
<b>ID</b>	<b>Component</b>	<b>Voltage</b>	<b>Current</b>	<b>Function</b>	<b>Comment</b>
D7-D12	FWD	1600 V	12 A	Rectifier Diode	
T1-T6	IGBT	1200 V	8 A	Inverter Switch	
D1-D6	FWD	1200 V	7,5 A	Inverter Diode	
R1-R3	Resistor			Inverter Shunt	
NTC	Thermistor			Thermistor	




Vincotech

20-1B12IPA008SC-L239C09  
20-FB12IPA008SC-L239C08Y  
datasheet

Packaging instruction			
Standard packaging quantity (SPQ) 100	>SPQ	Standard	<SPQ Sample

Handling instruction
Handling instructions for <i>flow</i> 1B packages see vincotech.com website.

Package data
Package data for <i>flow</i> 1B packages see vincotech.com website.

UL recognition and file number
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website. 

Document No.:	Date:	Modification:	Pages
20-xB12IPA008SC-L239C0xx-D2-14	26 July. 2019	Modified remark on Gate Driver, $V_{outFAULT}$ condition	6

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.